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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/777,325	02/06/2001	Toshihisa Suzuki	P/2007-79	2906
7590 05/05/2004			EXAMINER	
Steven I Weisburd Esq			CAO, ALLEN T	
Dickstein Shapiro Morin & Oshinsky LLP 1177 Avenue of the Americas			ART UNIT	PAPER NUMBER
41st Flort New York, NY 10036-2714			2652 DATE MAILED: 05/05/2004	11

Please find below and/or attached an Office communication concerning this application or proceeding.

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	Application No.	Applicant(s)			
	09/777,325	SUZUKI ET AL.			
Office Action Summary	Examiner	Art Unit			
	Allen T Cao	2652			
 The MAILING DATE of this communication app Period for Reply 	pears on the cover sheet with the c	orrespondence address			
A SHORTENED STATUTORY PERIOD FOR REPL' THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.1 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a repl - If NO period for reply is specified above, the maximum statutory period of the period of the period for reply within the set or extended period for reply will, by statute any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be time within the statutory minimum of thirty (30) day will apply and will expire SIX (6) MONTHS from the cause the application to become ABANDONE	nely filed s will be considered timely. the mailing date of this communication. D (35 U.S.C. § 133).			
Status	·				
1) Responsive to communication(s) filed on <u>07 Ja</u>	<u>anuary 2004</u> .				
2a)⊠ This action is FINAL . 2b)☐ This	action is non-final.				
3) Since this application is in condition for alloward closed in accordance with the practice under E	·				
Disposition of Claims					
4) ☐ Claim(s) 2 and 4-19 is/are pending in the appliance of the above claim(s) 2,4 and 6-15 is/are with 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 5,16 and 18 is/are rejected. 7) ☐ Claim(s) 17 and 19 is/are objected to. 8) ☐ Claim(s) are subject to restriction and/or	vithdrawn from consideration.				
Application Papers					
9) The specification is objected to by the Examine	er.				
10) The drawing(s) filed on is/are: a) accepted or b) objected to by the Examiner.					
Applicant may not request that any objection to the	drawing(s) be held in abeyance. See	e 37 CFR 1.85(a).			
Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the Ex	• • • • • • • • • • • • • • • • • • • •	•			
Priority under 35 U.S.C. § 119					
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority document application from the International Bureau * See the attached detailed Office action for a list	s have been received. s have been received in Applicati rity documents have been receive u (PCT Rule 17.2(a)).	on No ed in this National Stage			
Attachment(s)					
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date	4) Interview Summary Paper No(s)/Mail Da 5) Notice of Informal P 6) Other:				

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1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

2. Claims 5, 16 and 18 are rejected under 35 U.S.C. 103(a) as being unpatentable over Gill (US. 6,567,244 B1) in view of Sato et al (US. 6,710,986 B1).

Gill discloses a pair of magnetic tunnel junction structures (figure 11 and column 5, lines 30-32) as recited in claims 16 and 19.

Gill does not disclose the structure relationship of a barrier film, lower and upper magnetic layer, and an upper electrode electrically connected to the upper magnetic layer as set forth in claim 16.

Sato et al disclose a magnetic tunnel junction structure having a barrier film 310 sandwiched between a lower magnetic layer 210 and an upper magnetic layer 110, and an upper electrode electrically connected to the upper magnetic layer (see figure 2 shows that there is an electrode electrically connected to the layer 110), and a substrate 510.

It would have been obvious to one of ordinary skill in the art at the time the invention was made to modify/replace each magnetic tunnel junction of a pair of the magnetic tunnel junction structures of Gill with such combined structural of the magnetic tunnel junction structure as set forth, supra as taught by Sato et al to improve the outputs of the head in order to improve the read/write characteristics of the head.

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Regarding claim 18, Sato et al also disclose a conductive layer 410 (lead wire layer) provided on the substrate 510 and under the magnetic tunnel junction as described in the above.

Regarding claim 5, Sato et al disclose that the magnetic tunnel junction is formed by etching process on the conductive layer (column 14, lines 24-25).

However, Gill as modified by Sato et al do not disclose that the magnetic junction is formed by ion beam etching on the conductive layer.

It would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the magnetic tunnel junction of Gill as modified by Sato et al with an ion beam etching process on the conductive layer instead of an etching process.

The rationale is as follows: One of ordinary skill in the art would have been motivated to modify the magnetic tunnel junction of Gill as modified by Sato et al with an ion beam etching process on the conductive layer instead of an etching process as a result of routine engineering optimizing. Applicant has shown no criticality for such as any unexpected results deriving from such. Additionally, it is not found to be persuasive as a process limitation should only be accorded weight to the extent that it affects the structure of the completed magnetic tunnel junction structure since claims are directed to a "magnetic resistance device", per se. Furthermore, it should be noted that "[d]etermination of patentability in 'product-by-process' claims is based on product itself, even though such claims are limited and defined by process, and thus product in such claim is unpatentable if it is the same as, or obvious form, product of prior art, even

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if prior art product was made by a different process", <u>In re Thorpe, et al.</u>, 227 USPQ 964 (CAFC 1985). It should also be noted that a "[p]roduct-by process claim, although reciting subject matter of claim in terms of how it is made, is still product claim; it is patentability of product claimed and not recited process steps that must be established, in spite of fact that claim may recite only process limitations", <u>In re Hirao and Sato</u>, 190 USPQ 685.

- 3. Claims 17 and 19 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.
- 4. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of

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the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Applicant's amendment (newly amended claims 16-19) necessitated the new ground(s) of rejection presented in this Office action.

- 5. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. US006482657B2, US006469879B1, US006333842B1, US006639766B2, and US006563682B1.
- 6. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Allen T Cao whose telephone number is (703) 305-3796. The examiner can normally be reached on Mon Thurs (7:30 6:00).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Hoa T Nguyen can be reached on (703) 305-9687. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Allen Cao

Primary Examiner

Mladin

AC

April 27, 2004